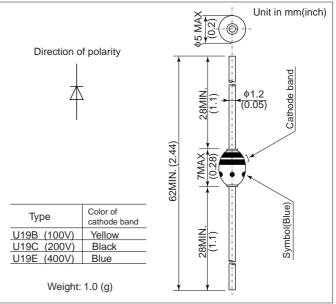


FEATURES

- For high speed switching.
- Diffused-junction. Glass passivated and encapsulated.

OUTLINE DRAWING



ABSOLUTE MAXIMUM RATINGS

Items	Туре		U19B	U19C	U19E			
Repetitive Peak Reverse Voltage	V_{RRM}	V	100	200	400			
Non-Repetitive Peak Reverse Voltage	V _{RSM}	V	200	300	500			
Average Forward Current	I _{F(AV)}	А	2.5 (Single-phase half sine wave 180° conduction) TL = 80° C, Lead length = 10 mm)					
Surge(Non-Repetitive) Forward Current	I _{FSM}	А	80(Without PIV, 10ms conduction, Tj = 150°C start)					
I ² t Limit Value	l ² t	A ² s	25.6(Time = 2 ~ 10ms, I = RMS value)					
Operating Junction Temperature	Tj	°C	-65 ~ +150					
Storage Temperature	T _{stg}	°C	-65 ~ +150					

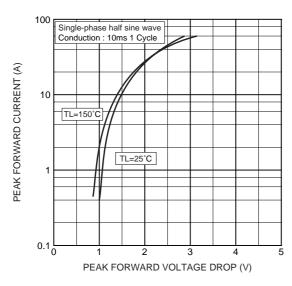
Notes (1) Lead mounting : Lead temperature 300°C max. to 3.2mm from body for 5sec. max.. (2) Mechanical strength : Bending 90°×2 cycles or 180°×1 cycle, Tensile 3kg, Twist 90°×1 cycle.

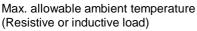
CHARACTERISTICS(T_L=25°C)

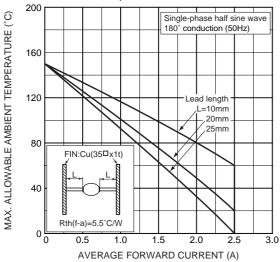
Items	Symbols	Units	Min.	Тур.	Max.	Test Conditions
Peak Reverse Current	I _{RRM}	μA	_	2.0	10	All class, Rated V_{RRM}
Peak Forward Voltage	V _{FM}	V	_	_	1.3	I_{FM} =2.5 Ap, Single-phase half sine wave 1 cycle
Reverse Recovery Time	trr	μs	_	_	0.2	I _F =2mA, V _R =-15V
Steady State Thermal Impedance	R _{th(j-a)} R _{th(j-l)}	°C/W	_	_	50 20	Lead length = 10 mm

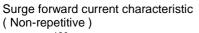
U19

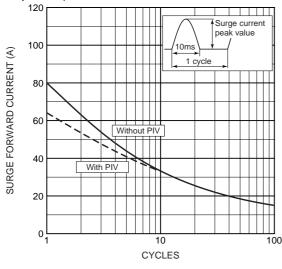
Forward characteristics



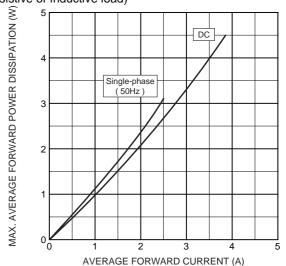




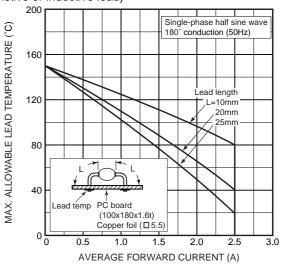




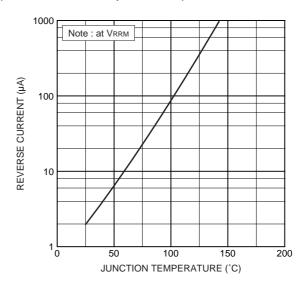
Max. average forward power dissipation (Resistive or inductive load)



Max. allowable lead temperature (Resistive or inductive load)



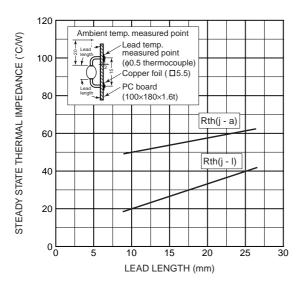
Typ. reverse current vs. junction temperature



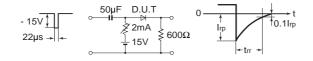
HITACHI

U19

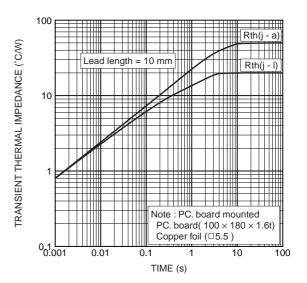
Steady state thermal impedance



Reverse recovery time(trr) test circuit



Transient thermal impedance



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HITACHI POWER SEMICONDUCTORS

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